PCN Number: 20220802			2000). 1		PCI	N Da	te:	August 03, 2022	
Title: Qualification of nev		w Fa	b site (FFAB) using qualified Process Technology, Die Revision,							
and additional Ass				y, Datasheet & BOI	4 options	s for	sele	ect devices		
Customer Contact:			PCN	<u>l Manager</u>		Dep	Dept: Quality Se		Quality Services	
Proposed 1 st Ship Date:		Oct	31, 2022	Sample Requests accepted until:		S	Sept 3, 2022*			
*Sa	*Sample requests received after Sept 3, 2022 will not be supported.									
Cha	ange Type:									
	Assembly Site		\boxtimes	Assembly Process			\boxtimes	Assembly Materials		
\boxtimes	Design		\boxtimes	Electrical Specification	ation			Mechanical Specification		
	Test Site			Packing/Shipping/Labeling				Test Process		
	Wafer Bump Sit	e	☐ Wafer Bump Material		rial			Wafer Bump Process		
\boxtimes	Wafer Fab Site		\boxtimes	☐ Wafer Fab Materials			\boxtimes	Wafei	Fab Process	
				Part number chan	ge					
	DCN Details									

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (FFAB, BICOM3XHV) die revision, and Assembly & BOM option for selected devices as listed below in the product affected section. Construction differences are noted below:

С	urrent Fab Site)	Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
SFAB	JI1	150 mm	FFAB	BICOM3XHV	200 mm

The die was also changed as a result of the process change.

Additionally, there will be a BOM/Assembly options introduced for these devices in Group 1 below:

	MLA Current	MLA Alternate
Bond wire composition, diameter	Au, 1.2 mils	Cu, 1.0 mil
Mold Compound	4209640	4226323
Mount Compound	4205846	4147858

The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The link to the revised datasheet is available in the table below.

 Added bandwice 	mboring format for to		I cross-references throughout the document1						
• Changed Appli	Added bandwidth and noise specifications in <i>Features</i>								
			Comparison Table						
			ım Ratings						
 Added note cla 	rifying output short-ci	rcuit "to ground" i	n Absolute Maximum Ratings refers to short-circuit to						
	upply appoification to								
	Added single supply specification to Recommended Operating Conditions								
Conditions	Changed input common-mode voltage range specification from V – 2 to (V–) + 2 in <i>Recommended Operating Conditions</i>								
Conditions									
			d Operating Conditions						
			otherwise noted" conditions in <i>Electrical</i>						
 Changed test c 	ondition for offset volt	tage drift specifica	ation in <i>Electrical Characteristics</i> from "T _A = T _{MIN}						
 Changed typical 	al long-term stability s	pecification from	±0.1±3/G μV/mo to ±0.2±3/G μV/mo in <i>Electrical</i>						
			/–) + 2 V minimum and (V+) – 2 V minimum across two						
			n across one row in <i>Electrical Characteristics</i>						
			in Electrical Characteristics						
			ge specification in <i>Electrical Characteristics</i> for clarity6						
 Added test con 	dition of " $T_A = -40$ °C	to +85°C" to inpu	it bias current drift specification in <i>Electrical</i>						
 Added test con 	dition of " $T_A = -40$ °C	to +85°C" to inpu	it offset current drift specification in <i>Electrical</i>						
 Changed maxir 	num gain error specif	ication for INA12	8PA/UA and INA129PA/UA with G = 1 from ±0.01%						
			n drift in <i>Electrical Characteristics</i> for clarityto "Positive output voltage swing" and from "Voltage -						
			rical Characteristics						
			swing specifications in Electrical Characteristics						
Added test con	dition of "Continuous		t-circuit current specification in Electrical Characteristic						
		f O 10 f-	for clarity6						
Changed typical bandwidth specification for G = 10 from 700 kHz to 640 kHz in <i>Electrical Characteristics</i> 6									
	al slew rate specificati								
Changed typica		ion from 4 V/µs to	ο 1.2 V/μs in <i>Electrical Characteristics</i>						
Changed typical Changed typical	al settling time specifi	ion from 4 V/µs to cation for G = 1, 0	o 1.2 V/µs in <i>Electrical Characteristics</i>						
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Changes from Revision E (April 2019) to Revision F (May 2022)

%253Dsearch-

everything%2526usecase%253DGPN

Page

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
☑ No Change	No Change	☑ No Change	No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

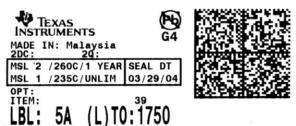
Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
SH-BIP-1	SHE	USA	Sherman
FFAB	FRE	DEU	Freising

Die Rev:

Current New

Die Rev [2P]	Die Rev [2P]
Е	A

Sample product shipping label (not actual product label)



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T) LOT: 3959047MLA (4W) TKY (1T) 7523483\$12 (P) (2P) REV: (V) 0033317 (20L) 898: SHE (21L) CCO: WSA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:						
Group 1 Device lis	st (Wafer fab, die revision	n, BOM and Datasheet ch	anges)			
INA128U	INA128UAE4	INA129U/2K5	INA128U/2K5G4			
INA129U	INA128UAG4	INA128UA/2K5	INA128UA/2K5E4			
INA128UA	INA129UAE4	INA129UA/2K5	INA128UA/2K5G4			
INA129UA	INA128U/2K5	INA128U-2/2K5	INA129UA/2K5G4			
INA128UG4						
Group 2 Device list (Datasheet changes only)						
INA128P	INA128PA	INA128PG4	INA129PG4			
ΙΝΔ129P	INA129PA					

For alternate parts with similar or improved performance, please visit the product page on $\overline{\text{TI.com}}$



TI Information Selective Disclosure

Qualification Report

Approve Date 01-Apr-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: INA128U	QBS Process Reference: <u>INA828ID</u>	QBS Package Reference: <u>INA849D</u>
HTOL	Life Test, 100CA	300 Hours	-	-	1/77/0
HTOL	Life Test, 150C	300 Hours	-	3/231/0	-
HBM	ESD - HBM	2000 V	1/3/0	1/3/0	1/3/0
CDM	ESD - CDM	1000 V	1/3/0	1/3/0	1/3/0
LU	Latch-up	JEDEC78	1/6/0	1/6/0	1/6/0
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	3/90/0	1/30/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	-
HBM	ESD - HBM	2000 V	1/3/0	1/3/0	1/3/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	3/231/0	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0	3/231/0
THB	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	-	-	3/231/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	3/231/0	3/231/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/ Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green A Tj of device at 150C

Change Number: C2011216 TI Qualification ID: 20201124-137263

- QBS: Qual By Similarity
- Qual Device INA128U is qualified at LEVEL2-260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green



TI Information **Selective Disclosure**

Qualification Report

Approve Date 01-Apr-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>INA129U</u>	QBS Product Reference: <u>INA128U</u>	QBS Process Reference: <u>INA828ID</u>	QBS Package Reference: <u>INA849D</u>
HTOL	Life Test, 100C A	300 Hours	-	-	-	1/77/0
HTOL	Life Test, 150C	300 Hours	-	-	3/231/0	-
HBM	ESD - HBM	2000 V	-	1/3/0	1/3/0	1/3/0
CDM	ESD - CDM	1000 V	-	1/3/0	1/3/0	1/3/0
LU	Latch-up	JEDEC78	-	1/6/0	1/6/0	1/6/0
ED	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	1/30/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	-
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	3/231/0	3/231/0
ТНВ	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	-	-	-	3/231/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	-	3/231/0	3/231/0
YLD	FTY and Bin Summary	-	1/Pass	-	-	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
 Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

ATj of device at 150C

TI Qualification ID: 20210624-140661

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
WW Change Management Team	PCN www admin_team@list.ti.com

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